

L Number	Hits	Search Text	US	Time stamp
1	1014128	memory adj cell and ferroelectric adj transistor and threshold aj voltage	USPAT; US-PGPUB; EPO; JPO	2002/12/11 16:45
2	38	memory adj cell and ferroelectric adj transistor and threshold adj voltage	USPAT; US-PGPUB; EPO; JPO	2002/12/11 16:45